Low capacitance 7-fold bidirectional ESD protection diode arrays

Rev. 4 — 23 June 2010

Product data sheet

1. Product profile

1.1 General description

Low capacitance 7-fold bidirectional ESD protection diode arrays in small plastic packages designed for the protection of up to seven transmission or data lines from damage caused by ElectroStatic Discharge (ESD) and other transients.

Table 1. Product overview

Type number	Package								
	Name	NXP							
PESD5V0L7BAS	TSSOP8	SOT505-1							
PESD5V0L7BS	SO8	SOT96-1							

1.2 Features and benefits

- ESD protection of up to seven lines
- Low diode capacitance
- Max. peak pulse power: P_{PP} = 35 W
- Low clamping voltage: V_{CL} = 17 V
- Ultra low leakage current: I_{RM} = 3 nA
- ESD protection of up to 10 kV
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge); I_{PP} = 2.5 A

1.3 Applications

- Computers and peripherals
- Communication systems
- Audio and video equipment
- High-speed data lines
- Parallel ports

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage		-	-	5	V
C _d	diode capacitance	$V_R = 0 V;$ f = 1 MHz	-	8	10	pF



2. Pinning information

Table 3. Pinning

Table 3.	Filling		
Pin	Description	Simplified outline	Graphic symbol
TSSOP8			
1	cathode 1		
2	cathode 2	8	1 8
3	cathode 3		2 7
4	cathode 4		
5	cathode 5		$\frac{3}{2}$
6	cathode 6	1	4 1 5
7	cathode 7		
8	cathode 8		sym005
S08			
1	cathode 1		
2	cathode 2	8 <u>7</u> <u>7</u> <u>7</u> <u>7</u> 5	1 1 8
3	cathode 3		2 7
4	cathode 4		
5	cathode 5	1	3 K B 6
6	cathode 6		4 4 5
7	cathode 7		
8	cathode 8		sym005

3. Ordering information

Table 4. Ordering information

Type number	Package										
	Name	Description	Version								
PESD5V0L7BAS	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm	SOT505-1								
PESD5V0L7BS	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1								

4. Marking

Table 5. Marking codes

Type number	Marking code
PESD5V0L7BAS	5V07B
PESD5V0L7BS	5V0L7BS

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
P_{PP}	peak pulse power	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	35	W
I _{PP}	peak pulse current	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	2.5	Α
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Non-repetitive current pulse 8/20 μ s exponentially decaying waveform according to IEC 61000-4-5; see Figure 1.

Table 7. ESD maximum ratings

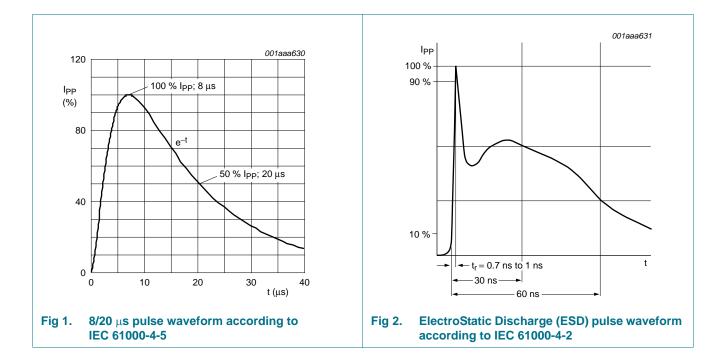
	_				
Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1]</u> _	10	kV
		MIL-STD-883 (human body model)	-	10	kV

^[1] Device stressed with ten non-repetitive ElectroStatic Discharge (ESD) pulses; see Figure 2.

Table 8. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD); see Figure 2	> 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

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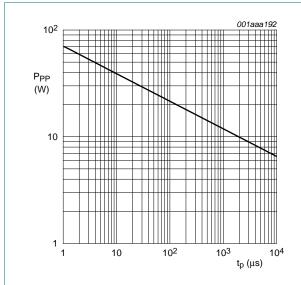
6. Characteristics

Table 9. Characteristics

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V_{RWM}	reverse standoff voltage		-	-	5	V
I _{RM}	reverse leakage current	V _{RWM} = 5 V; see <u>Figure 6</u>	-	3	25	nΑ
V_{CL}	clamping voltage	I _{PP} = 1 A	<u>[1]</u> -	-	11	V
V _{RWM} I I _{RM} I V _{CL} I V _{BR} I r _{dif} I		I _{PP} = 2.5 A	<u>[1]</u> -	-	17	V
V_{BR}	breakdown voltage	I _R = 1 mA	7.2	7.6	7.9	V
r _{dif}	differential resistance	I _R = 1 mA	-	-	100	Ω
C _d	diode capacitance	$V_R = 0 \text{ V; } f = 1 \text{ MHz;}$ see Figure 5	-	8	10	pF

[1] Non-repetitive current pulse 8/20 µs exponentially decaying waveform according to IEC 61000-4-5; see Figure 1.



 $T_{amb} = 25 \, ^{\circ}C$

Fig 3. Peak pulse power as a function of exponential pulse duration t_p; typical values

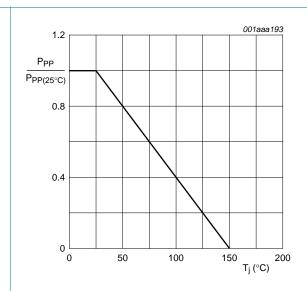
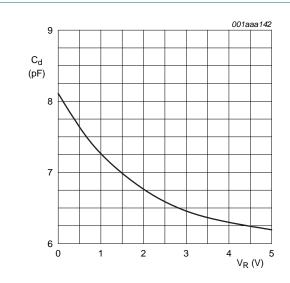


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$

Fig 5. Diode capacitance as a function of reverse voltage; typical values

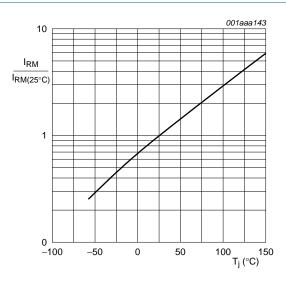
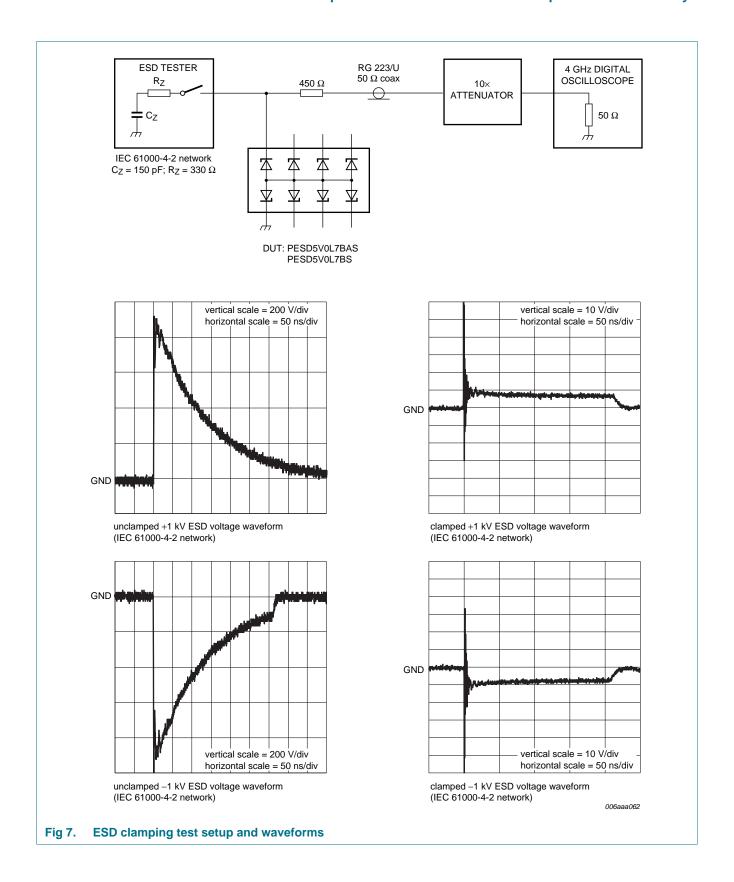


Fig 6. Relative variation of reverse leakage current as a function of junction temperature; typical values

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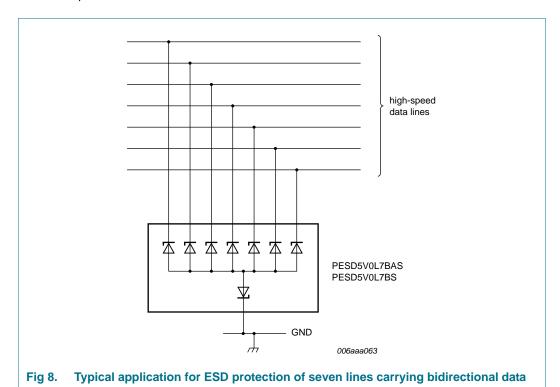


Product data sheet

7. Application information

The PESD5V0L7BAS and the PESD5V0L7BS are designed for the protection of up to seven bidirectional data lines from the damage caused by ElectroStatic Discharge (ESD) and surge pulses. The PESD5V0L7BAS and the PESD5V0L7BS may be used on lines where the signal polarities are above and below ground.

The PESD5V0L7BAS and the PESD5V0L7BS provide a surge capability of 35 W per line for a $8/20~\mu s$ waveform.



Circuit board layout and protection device placement:

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

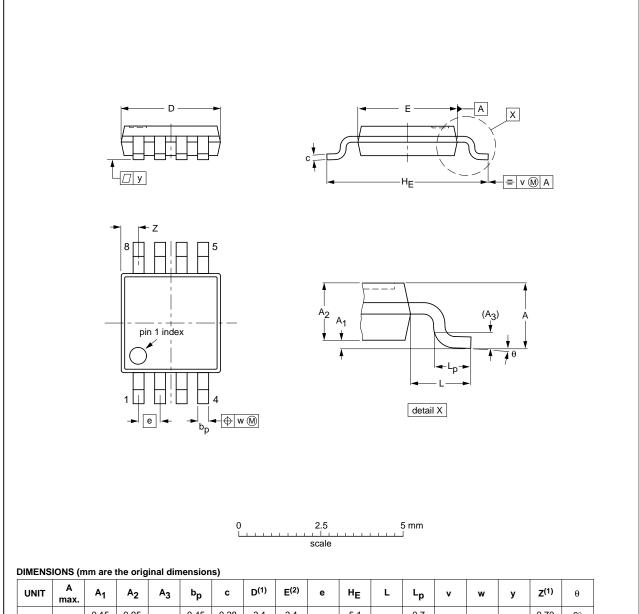
- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

PESD5V0L7BAS_BS

Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm

SOT505-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.45 0.25	0.28 0.15	3.1 2.9	3.1 2.9	0.65	5.1 4.7	0.94	0.7 0.4	0.1	0.1	0.1	0.70 0.35	6° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

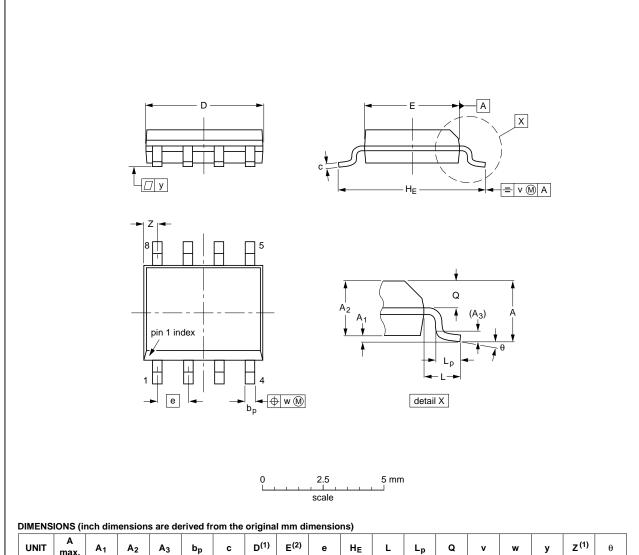
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	13302 DATE	
SOT505-1						99-04-09 03-02-18	

Package outline SOT505-1 (TSSOP8) Fig 9.

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SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



UNIT	A max.	A ₁	A ₂	Α3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.20 0.19	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT96-1	076E03	MS-012				99-12-27 03-02-18

Fig 10. Package outline SOT96-1 (SO8/MS-012)

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9. Packing information

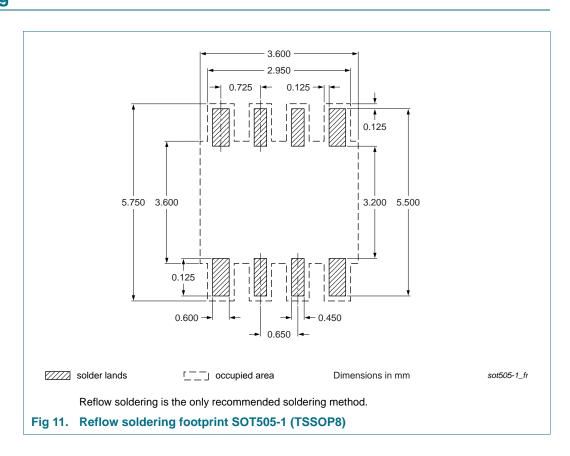
Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

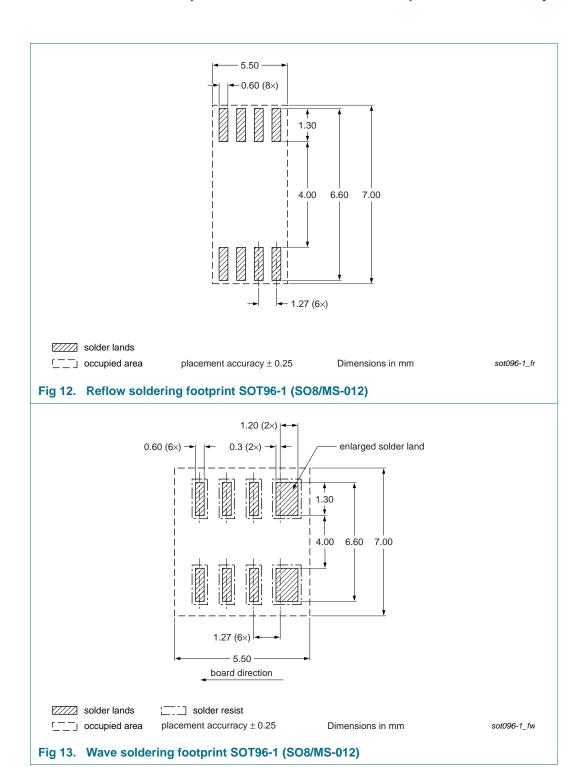
Type number	Package	Description Packing		uantity
			1000	2500
PESD5V0L7BAS	SOT505-1	8 mm pitch, 12 mm tape and reel	· -	-118
PESD5V0L7BS	SOT96-1	8 mm pitch, 12 mm tape and reel	-115	-118

^[1] For further information and the availability of packing methods, see Section 13.

10. Soldering



Low capacitance 7-fold bidirectional ESD protection diode arrays



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11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0L7BAS_BS v.4	20100623	Product data sheet	-	PESD5V0L7BAS_BS_3
Modifications:	 Section 4 "Mar 	king": marking code correct	ted for PESD5V0L7B	AS
	 Section 10 "So 	ldering": added		
	 Section 12 "Le 	gal information": updated		
PESD5V0L7BAS_BS_3	20090820	Product data sheet	-	PESD5V0L7BAS_BS_2
PESD5V0L7BAS_BS_2	20041125	Product data sheet	-	PESD5V0L7BS_1
PESD5V0L7BS_1	20040315	Product specification	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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